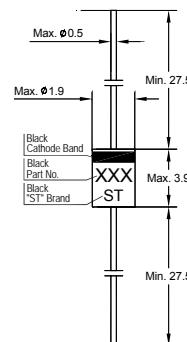


1N914, 1N914A, 1N914B

FAST SWITCHING DIODES

Features

- Fast Switching Speed
- High Reliability



Glass Case DO-35
Dimensions in mm

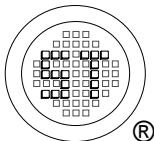
Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Non-Repetitive Peak Reverse Voltage	V_{RM}	100	V
Peak Repetitive Reverse Voltage	V_{RRM}		
Working Peak Reverse Voltage	V_{RWM}	75	V
DC Blocking Voltage	V_R		
RMS Reverse Voltage	$V_{R(RMS)}$	53	V
Average Rectified Output Current ¹⁾	I_o	75 200	mA
1N914 1N914A / B			
Forward Continuous Current ¹⁾	I_{FM}	150 300	mA
1N914 1N914A / B			
Non-Repetitive Peak Forward Surge Current at $t = 1\text{ s}$	I_{FSM}	1	A
1N914 at $t = 1\text{ }\mu\text{s}$		1	
1N914A / B at $t = 1\text{ }\mu\text{s}$		4	
Power Dissipation ¹⁾	P_{tot}	500	mW
Thermal Resistance, Junction to Ambient Air ¹⁾	$R_{\theta JA}$	300	K/W
Operating and Storage Temperature Range	T_j, T_s	- 65 to + 175	°C

Characteristics at $T_a = 25^\circ\text{C}$

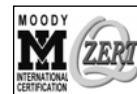
Parameter	Symbol	Min.	Max.	Unit
Forward Voltage at $I_F = 5\text{ mA}$	V_F	0.62	0.72	V
1N914B		-	1	
at $I_F = 100\text{ mA}$		-	1	
1N914B		-	1	
at $I_F = 10\text{ mA}$		-	1	
1N914		-	1	
at $I_F = 20\text{ mA}$		-	1	
1N914A		-	1	
Reverse Current at $V_R = 20\text{ V}$	I_R	-	25	nA
at $V_R = 75\text{ V}$		-	5	µA
at $V_R = 20\text{ V}, T_j = 150^\circ\text{C}$		-	50	µA
Diode Capacitance at $V_R = 0, f = 1\text{ MHz}$	C_j	-	4	pF
Reverse Recovery Time at $I_F = 10\text{ mA}$ to $I_R = 1\text{ mA}, V_R = 6\text{ V}, R_L = 100\text{ }\Omega$	t_{rr}	-	4	ns

¹⁾ Valid provided that lead are kept at ambient temperature at a distance of 8 mm.



SEMTECH ELECTRONICS LTD.

(Subsidiary of Sino-Tech International Holdings Limited, a company listed on the Hong Kong Stock Exchange, Stock Code: 724)



ISO/TS 16949 : 2002
Certificate No. 05103



ISO 14001:2004
Certificate No. 7116



ISO 9001:2000
Certificate No. 0506098

Dated : 13/06/2007